Serial No.: 10/807,545 Filed: March 24, 2004

Page : 2 of 15

Amendments to the Claims

This listing of claims replaces all prior versions and listings of claims in the application.

Listing of Claims:

- 1. (Currently Amended) A light-emitting device comprising:
- a first pixel comprising:
 - a first light-emitting element,
- a first transistor for determining a value of a current flowing to the <u>first</u> lightemitting element, and
- a second transistor for determining a light emission or non light emission of the <u>first light-emitting element depending on a first video signal input through a first signal line[[,]];</u> a second pixel comprising:
 - a second light-emitting element,
- a third transistor for determining a value of a current flowing to the second lightemitting element, and
- a fourth transistor for determining a light emission or non light emission of the second light-emitting element depending on a second video signal input through a second signal line; and
 - a third pixel comprising:
 - a third light-emitting element,
- a fifth transistor for determining a value of a current flowing to the third lightemitting element, and
- a sixth transistor for determining a light emission or non light emission of the third light-emitting element depending on a third video signal input through a third signal line,
- wherein the <u>first</u> light-emitting element, the first transistor, and the second transistor are connected in series between a first power line and a counter electrode of the <u>first</u> light-emitting element,

wherein a gate electrode of the first transistor is connected to a second power line,

Serial No.: 10/807,545 Filed: March 24, 2004

Page : 3 of 15

wherein the second light-emitting element, the third transistor, and the fourth transistor are connected in series between a third power line and a counter electrode of the second light-emitting element,

wherein a gate electrode of the third transistor is connected to a fourth power line,
wherein the third light-emitting element, the fifth transistor, and the sixth transistor are
connected in series between a fifth power line and a counter electrode of the third light-emitting
element,

wherein a gate electrode of the fifth transistor is connected to a sixth power line, and wherein electric potentials of each of the second power line, the fourth power line and the sixth power line are different from electric potentials of the other two. wherein the signal line, the first power line, and the second power line are provided in parallel with each other,

wherein the first power line is provided between the signal line and the second power line, and

wherein the second power line has an electric potential so that the first transistor operates in a saturation region when the second transistor is in an on-state.

- 2. (Currently Amended) A light-emitting device comprising:
- a first pixel comprising:
 - a first light-emitting element,
- a first transistor for determining a value of a current flowing to the <u>first</u> lightemitting element,
- a second transistor for determining a light emission or non light emission of the <u>first</u> light-emitting element depending on a <u>first</u> video signal input through a <u>first</u> signal line, and a third transistor for controlling an input of the first video signal[[,]];

a second pixel comprising:

- a second light-emitting element,
- a fourth transistor for determining a value of a current flowing to the second lightemitting element.

Serial No.: 10/807,545 Filed: March 24, 2004

Page : 4 of 15

a fifth transistor for determining a light emission or non light emission of the second light-emitting element depending on a second video signal input through a second signal line, and

a sixth transistor for controlling an input of the second video signal; and a third pixel comprising:

a third light-emitting element,

a seventh transistor for determining a value of a current flowing to the third lightemitting element,

a eighth transistor for determining a light emission or non light emission of the third light-emitting element depending on a third video signal input through a third signal line, and

a ninth transistor for controlling an input of the third video signal,

wherein the <u>first</u> light-emitting element, the first transistor, and the second transistor are connected in series between a first power line and a counter electrode of the <u>first</u> light-emitting element,

wherein a gate electrode of the first transistor is connected to a second power line,

wherein the second light-emitting element, the fourth transistor, and the fifth transistor

are connected in series between a third power line and a counter electrode of the second light
emitting element,

wherein a gate electrode of the fourth transistor is connected to a fourth power line,
wherein the third light-emitting element, the seventh transistor, and the eighth transistor
are connected in series between a fifth power line and a counter electrode of the third lightemitting element,

wherein a gate electrode of the seventh transistor is connected to a sixth power line, and wherein electric potentials of each of the second power line, the fourth power line and the sixth power line are different from electric potentials of the other two. wherein the signal line, the first power line, and the second power line are provided in parallel with each other,

wherein the first power line is provided between the signal line and the second power line, and

Serial No.: 10/807,545 Filed: March 24, 2004

Page : 5 of 15

wherein the second power-line has an electric potential so that the first transistor operates in a saturation region when the second transistor is in an on-state.

3. (Previously Presented) A light-emitting device comprising:

a pixel comprising:

a light-emitting element,

a first transistor for determining a value of a current flowing to the light-emitting element,

a second transistor for determining a light emission or non light emission of the light-emitting element depending on a video signal input through a signal line,

a third transistor for controlling an input of the video signal, and

a fourth transistor for forcing the light-emitting element into a non-emission state irrelevant from the video signal,

wherein the light-emitting element, the first transistor, and the second transistor are connected in series between a first power line and a counter electrode of the light-emitting element,

wherein a gate electrode of the first transistor is connected to a second power line, wherein the signal line, the first power line, and the second power line are provided in parallel with each other,

wherein the first power line is provided between the signal line and the second power line, and

wherein the second power line has an electric potential so that the first transistor operates in a saturation region when the second transistor is in an on-state.

- 4. (Previously Presented) The light-emitting device according to claim 1, wherein the first transistor and the second transistor are identical in conductivity.
- 5. (Currently Amended) The light-emitting device according to claim 1, wherein the first transistor comprises is a depletion type transistor.

Serial No.: 10/807,545 Filed: March 24, 2004

Page : 6 of 15

6. (Previously Presented) The light-emitting device according to claim 1, wherein the first transistor has a channel length longer than a channel width, and the second transistor has a channel length equal to or shorter than a channel width.

- 7. (Previously Presented) The light-emitting device according to claim 6, wherein a ratio of the channel length to the channel width of the first transistor is 5 or more.
 - 8. (Currently Amended) An element substrate comprising:
 - a first pixel comprising:
 - a first pixel electrode;
- a first transistor for determining a value of a current flowing to the <u>first pixel</u> electrode, and
- a second transistor for determining a supply or non-supply of a current to the <u>first</u> pixel electrode depending on a <u>first</u> video signal input through a <u>first</u> signal line[[,]];

a second pixel comprising:

a second pixel electrode;

a third transistor for determining a value of a current flowing to the second pixel electrode, and

a fourth transistor for determining a supply or non-supply of a current to the second pixel electrode depending on a second video signal input through a second signal line; and

a third pixel comprising:

a third pixel electrode;

<u>a fifth transistor for determining a value of a current flowing to the third pixel</u> electrode, and

a sixth transistor for determining a supply or non-supply of a current to the third pixel electrode depending on a third video signal input through a third signal line,

wherein the first transistor and the second transistor are connected in series between a first power line and the <u>first pixel</u> electrode,

wherein a gate electrode of the first transistor is connected to a second power line,

Serial No.: 10/807,545 Filed: March 24, 2004

Page : 7 of 15

wherein the third transistor and the fourth transistor are connected in series between a third power line and the second pixel electrode,

wherein a gate electrode of the third transistor is connected to a fourth power line,
wherein the fifth transistor and the sixth transistor are connected in series between a fifth
power line and the third pixel electrode,

wherein a gate electrode of the fifth transistor is connected to a sixth power line, and wherein electric potentials of each of the second power line, the fourth power line and the sixth power line are different from electric potentials of the other two. wherein the signal line, the first power line, and the second power line are provided in parallel with each other,

wherein the first power line is provided between the signal line and the second power line, and

wherein the second power line has an electric potential so that the first transistor operates in a saturation region when the second transistor is in an on-state.

- 9. (Previously Presented) The element substrate according to claim 8, wherein each of the first transistor and the second transistor has a P-type conductivity, and a threshold value of the first transistor is higher than that of the second transistor.
- 10. (Previously Presented) The element substrate according to claim 8, wherein each of the first transistor and the second transistor has an N-type conductivity, and a threshold value of the first transistor is lower than that of the second transistor.
- 11. (Currently Amended) The element substrate according to claim 8, wherein the first transistor comprises is a depletion type transistor.
- 12. (Previously Presented) The element substrate according to claim 8, wherein the first transistor has a channel length longer than a channel width, and the second transistor has a channel length equal to or shorter than a channel width.

Serial No.: 10/807,545 Filed: March 24, 2004

Page : 8 of 15

13. (Previously Presented) The element substrate according to claim 12, wherein a ratio of the channel length to the channel width of the first transistor is 5 or more.

- 14. (Previously Presented) The light-emitting device according to claim 2, wherein the first transistor and the second transistor are identical in conductivity.
- 15. (Previously Presented) The light-emitting device according to claim 3, wherein the first transistor and the second transistor are identical in conductivity.
- 16. (Currently Amended) The light-emitting device according to claim 2, wherein the first transistor comprises is a depletion type transistor.
- 17. (Currently Amended) The light-emitting device according to claim 3, wherein the first transistor comprises is a depletion type transistor.
- 18. (Previously Presented) The light-emitting device according to claim 2, wherein the first transistor has a channel length longer than a channel width, and the second transistor has a channel length equal to or shorter than a channel width.
- 19. (Previously Presented) The light-emitting device according to claim 3, wherein the first transistor has a channel length longer than a channel width, and the second transistor has a channel length equal to or shorter than a channel width.
- 20. (Currently Amended) The element substrate according to claim 9, wherein the first transistor comprises is a depletion type transistor.
- 21. (Currently Amended) The element substrate according to claim 10, wherein the first transistor <u>comprises is a depletion type transistor</u>.

Applicant : Mitsuaki Osame et al.

Serial No. : 10/807,545

Attorney's Docket No.: 127320223001 / US7068/7143/7203

Serial No.: 10/807,545 Filed: March 24, 2004

Page : 9 of 15

22. (Previously Presented) The element substrate according to claim 9, wherein the first transistor has a channel length longer than a channel width, and the second transistor has a channel length equal to or shorter than a channel width.

- 23. (Previously Presented) The element substrate according to claim 10, wherein the first transistor has a channel length longer than a channel width, and the second transistor has a channel length equal to or shorter than a channel width.
- 24. (Previously Presented) The light-emitting device according to claim 18, wherein a ratio of the channel length to the channel width of the first transistor is 5 or more.
- 25. (Previously Presented) The light-emitting device according to claim 19, wherein a ratio of the channel length to the channel width of the first transistor is 5 or more.
- 26. (Previously Presented) The light-emitting device according to claim 1, wherein the light-emitting device is incorporated into at least one selected from the group consisting of a cellular phone, a mobile computer, a game machine, an electronic book, a video camera, a digital camera, a goggle display, a display device, and a navigation system.
- 27. (Previously Presented) The light-emitting device according to claim 2, wherein the light-emitting device is incorporated into at least one selected from the group consisting of a cellular phone, a mobile computer, a game machine, an electronic book, a video camera, a digital camera, a goggle display, a display device, and a navigation system.
- 28. (Previously Presented) The light-emitting device according to claim 3, wherein the light-emitting device is incorporated into at least one selected from the group consisting of a cellular phone, a mobile computer, a game machine, an electronic book, a video camera, a digital camera, a goggle display, a display device, and a navigation system.

Serial No.: 10/807,545 Filed: March 24, 2004

Page : 10 of 15

29. (Previously Presented) The element substrate according to claim 8, wherein the element substrate is incorporated into at least one selected from the group consisting of a cellular phone, a mobile computer, a game machine, an electronic book, a video camera, a digital camera, a goggle display, a display device, and a navigation system.

- 30. (Currently Amended) The light-emitting device according to claim 1, wherein the electric potential potentials of the second power line, the fourth power line and the sixth power line [[is]] are fixed.
- 31. (Currently Amended) The light-emitting device according to claim 2, wherein the electric potential potentials of the second power line, the fourth power line and the sixth power line [[is]] are fixed.
- 32. (Previously Presented) The light-emitting device according to claim 3, wherein the electric potential of the second power line is fixed.
- 33. (Currently Amended) The element substrate according to claim 8, wherein the electric potential potentials of the second power line, the fourth power line and the sixth power line [[is]] are fixed.